Shenzhen Toby Technology Co., Ltd.

Report No.: TB-MPE147356

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RF Exposure Evaluation FCC ID: 2AHYHHFD-810A

1. Client Information

Applicant: Shenzhen Hi-FiD Electronics Tech Co., Ltd

Address: 4F, B7 Building, Hengfeng industrial City, Hezhou Village, Xixiang Town,

Bao'an District, Shenzhen City, China

Manufacturer : Shenzhen Hi-FiD Electronics Tech Co., Ltd

Address: 4F, B7 Building, Hengfeng industrial City, Hezhou Village, Xixiang Town,

Bao'an District, Shenzhen City, China

2. General Description of EUT

EUT Name		Bluetooth Speaker				
Models No.	:	HFD-810A ,BP-WANTS, SP-SKBT810, SP-SKBT812, SP-SKBEAST, HFD-895, HFD-896, HFD-810, HFD-812, WSP-895				
Model Difference	Š	All these models are identical in the same PCB, layout and electrical circuit, the only difference is model name for commercial.				
Product Description		Operation Frequency: Bluetooth 4.0: 2402~2480MHz				
	A	Number of Channel:	Bluetooth:79 Channels BLE: 40 Channels			
		Max Peak Output Power:	Bluetooth: 3.782 dBm(8-DPSK) BLE: 3.820 dBm			
		Antenna Gain:	0.5 dBi PCB Antenna			
		Modulation Type:	GFSK 1Mbps(1 Mbps&BLE) π /4-DQPSK(2 Mbps) 8-DPSK(3 Mbps)			
Power Supply	:	DC power by AC/DC Adapter.				
		DC power by Li-ion Battery.				
Power Rating		Input: AC 100-240V~50/60Hz 0.6A. Output: 15V,1500mA. DC 11.1V by 2250mAh Li-ion Battery.				
Connecting I/O Port(S)	:	Please refer to the User's Manual				

Note:

More test information about the EUT please refer the RF Test Report.

TB-RF-074-1. 0

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SAR Test Exclusion Calculations

1. FCC: According to KDB 447498 D01 Mobile and Portable Devices RF Exposure Procedures and Equipment Authorization Policies v05r02.

- (1) Clause 4.3: General SAR test reduction and exclusion guidance Sub clause 4.31: Standalone SAR test exclusion considerations
 - 1)The 1-g and 10-g SAR test exclusion thresholds for 100 MHz to 6GHz at test separation distance≤5 mm are determined by:

[(max. power of channel, including tune-up tolerance, mW)/(min. test separation, mm)]*[$\sqrt{f_{(GHz)}}$] \leq 3.0 for 1-g SAR

[(max. power of channel, including tune-up tolerance, mW)/(min. test separation, mm)]*[$\sqrt{f_{(GHz)}}$] \leq 7.5.0 for 10-g SAR



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2. Calculation:

est separation	n: 5mm				
		Bluetooth Mode	e (GFSK)	3	W
Frequency (GHz)	Conducted Power (dBm)	Turn-up Power Tolerance (dB)	Max power of tune up tolerance (mw)	Calculation Value	Threshold Value
2.402	0.816	±0.5	1.354	0.420	3.0
2.441	3.288	±0.5	2.392	0.748	3.0
2.480	2.041	±0.5	1.795	0.565	3.0
		Bluetooth Mode (π /4-DQPSK)	TO CO	
Frequency (GHz)	Conducted Power (dBm)	Turn-up Power Tolerance (dB)	Max power of tune up tolerance (mw)	Calculation Value	Threshold Value
2.402	2.509	±0.5	1.999	0.620	3.0
2.441	1.248	±0.5	1.496	0.467	3.0
2.480	3.241	±0.5	2.366	0.745	3.0
nn)	133	Bluetooth Mode	e (8-DPSK)	1777 V	600
Frequency (GHz)	Conducted Power (dBm)	Turn-up Power Tolerance (dB)	Max power of tune up tolerance (mw)	Calculation Value	Threshold Value
2.402	2.978	±0.5	2.227	0.690	3.0
2.441	1.743	±0.5	1.676	0.524	3.0
2.480	3.782	±0.5	2.680	0.844	3.0
MIN'S		WILL STATE			
Frequency (GHz)	Conducted Power (dBm)	Turn-up Power Tolerance (dB)	Max power of tune up tolerance (mw)	Calculation Value	Threshold Value
2.402	3.820	±0.5	2.704	0.838	3.0
2.441	2.642	±0.5	2.062	0.644	3.0
2.480	1.499	±0.5	1.585	0.499	3.0

So standalone SAR measurements are not required.